

Evidence for a new symmetry breaking mechanism reorienting quantum Hall nematics

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We report on the effect of in-plane magnetic field B_{\parallel} on stripe phases in higher ($N = 2, 3$) Landau levels of a high-mobility two-dimensional electron gas. In accord with previous studies, we find that a modest B_{\parallel} applied parallel to the native stripes aligns them perpendicular to it. However, upon further increase of B_{\parallel} , stripes are reoriented back to their native direction. Remarkably, applying B_{\parallel} perpendicular to the native stripes also aligns stripes parallel to it. Thus, regardless of the initial orientation of stripes with respect to B_{\parallel} , stripes are ultimately aligned *parallel* to B_{\parallel} . These findings provide evidence for a B_{\parallel} -induced symmetry-breaking mechanism which challenge current understanding of the role of B_{\parallel} and should be taken into account when determining the strength of the native symmetry-breaking potential. Finally, our results might indicate nontrivial coupling between the native and external symmetry-breaking fields, which has not yet been theoretically considered.

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Electronic liquid crystal-like phases, termed electron nematics or stripes, are expected to form in a wide variety of condensed matter systems [1–5]. A two-dimensional electron gas in GaAs/AlGaAs hosts the first, and perhaps the most striking, realization of such phases [6–11]. Stripes in a two-dimensional electron gas form due to interplay between exchange and direct Coulomb interactions [6,7,10,11] and are manifested by the resistivity minima (maxima) in the easy (hard) transport direction near half-integer filling factors, $\nu = 9/2, 11/2, 13/2, \dots$ when the system is cooled below $T \approx 0.1$ K. With very few exceptions [12–14], stripes in GaAs are aligned along the (110) direction, but what exactly causes such orientation remains unknown [13,15,16].

While the origin of the native symmetry-breaking potential responsible for preferred stripes orientation remains elusive, its magnitude was routinely obtained from experiments employing in-plane magnetic field B_{\parallel} which provides an external symmetry-breaking field competing with and overcoming the native one. Our current understanding of B_{\parallel} -induced symmetry-breaking potential is based on finite thickness effects [17,18], which favor stripes perpendicular to B_{\parallel} , consistent with previous experiments [13,19–23]. The same approach successfully explains B_{\parallel} -induced stripes in both single-subband [19,20,24–26] and double-subband [27] systems.

In this Rapid Communication we reexamine the effect of in-plane magnetic field on quantum Hall stripes in ultrahigh-quality GaAs quantum wells. In agreement with early experiments [19–21], we find that a $B_{\parallel} \lesssim 0.4$ applied parallel to the native stripes aligns stripes perpendicular to it. Remarkably, upon further increase of B_{\parallel} , stripes are reoriented back to their native direction, i.e., *parallel* to B_{\parallel} . When B_{\parallel} is applied perpendicular to the native stripes, we also find that stripes are reoriented *parallel* to B_{\parallel} . We thus conclude that there exist a new B_{\parallel} -induced symmetry-breaking potential which challenge our understanding of the role of B_{\parallel} and must be taken into

account when determining the strength of the native symmetry-breaking potential. In contrast to the well-established B_{\parallel} -induced symmetry-breaking potential originating from finite thickness effects, new symmetry-breaking potential exhibits high sensitivity to spin and Landau level indices. Finally, our results suggest a nontrivial coupling between the native and external symmetry-breaking fields, which has not yet been theoretically considered and might provide an important clue to unveiling the origin of the native symmetry-breaking potential.

The sample used in our study is a 4×4 mm square cleaved from a symmetrically doped, 30-nm-wide GaAs/AlGaAs quantum well. Electron density and mobility were $n_e \approx 2.9 \times 10^{11}$ cm⁻² and $\mu \approx 1.6 \times 10^7$ cm²/V s, respectively. Eight indium contacts were fabricated at the corners and mid-sides of the sample. The longitudinal resistances, R_{xx} and R_{yy} , were measured using four-terminal, low-frequency lock-in technique; the current (typically 10 nA) was sent through the mid-side contacts and the voltage drop was recorded between the corner contacts. An in-plane magnetic field was introduced by tilting the sample about \hat{x} or \hat{y} axis, in two separate cooldowns. The data were taken at $T \approx 20$ mK.

In Fig. 1(a) we present an example of stripes in perpendicular magnetic field near $\nu = 9/2$, characterized by $R_{xx} \gg R_{yy}$, indicating stripes oriented along $\hat{y} \equiv \langle 110 \rangle$ direction. When B_{\parallel} is applied parallel to the native stripes ($B_{\parallel} = B_y$), at $\theta_y = 12^\circ$ stripes reorient along the \hat{x} direction (perpendicular to B_{\parallel}), as anticipated [see Fig. 1(b)]. Surprisingly, upon further increase of B_y , at $\theta_y = 46^\circ$ stripes are reoriented again, back to their native direction and are now aligned *parallel* to B_{\parallel} [see Fig. 1(c)]. When B_{\parallel} is applied perpendicular to the native stripes ($B_{\parallel} = B_x$), at $\theta_x = 42^\circ$ stripes are reoriented along the \hat{x} direction, again aligning *parallel* to B_{\parallel} [see Fig. 1(d)]. We thus conclude that, regardless of the orientation of B_{\parallel} , ultimately, stripes align *parallel* to B_{\parallel} .

Figure 1(e) shows the resistance anisotropy $A_R \equiv (R_{xx} - R_{yy})/(R_{xx} + R_{yy})$ vs B_x (left panel) and B_y (right panel). Starting from $A_R \approx 1$, with increasing B_y , A_R vanishes at $B_y \approx 0.4$ T, reaches $A_R \approx -1$, turns around, disappears again

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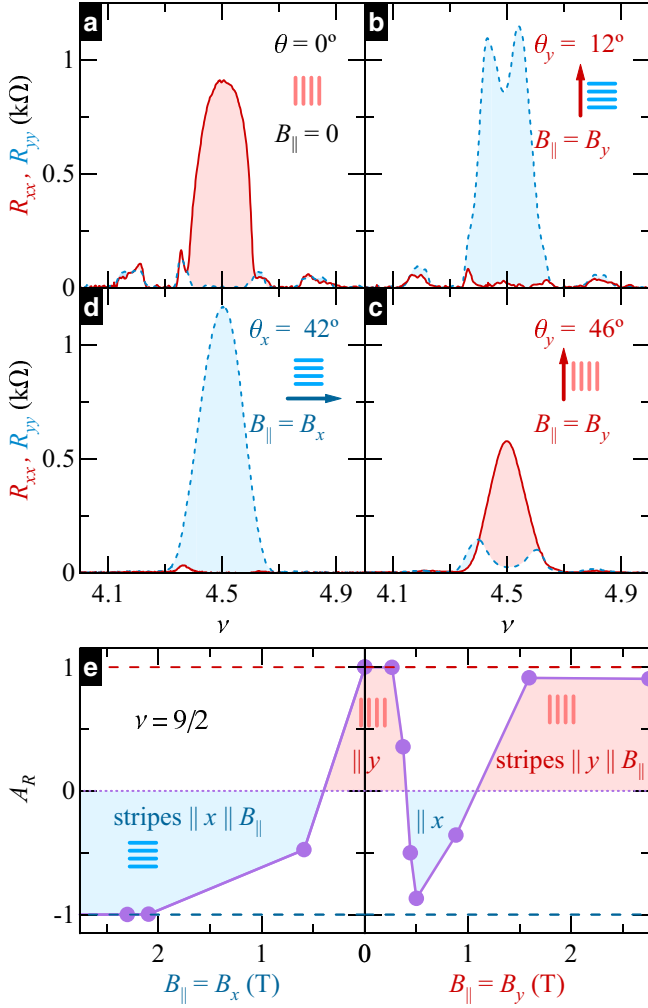


FIG. 1. R_{xx} (solid line) and R_{yy} (dotted line) versus ν at (a) $\theta = 0^\circ$, (b) $B_{\parallel} = B_y$ and $\theta_y = 12^\circ$, (c) $B_{\parallel} = B_y$ and $\theta_y = 46^\circ$, and (d) $B_{\parallel} = B_x$ and $\theta_x = 42^\circ$. (e) Resistance anisotropy $A_R \equiv (R_{xx} - R_{yy}) / (R_{xx} + R_{yy})$ as a function of $B_{\parallel} = B_x$ (left) and $B_{\parallel} = B_y$ (right) at $\nu = 9/2$. The inset shows the stripes orientation and the direction of B_{\parallel} .

at $B_y \approx 1.1$ T, and finally returns to $A_R \approx 1$. With increasing B_x , A_R vanishes at $B_x \approx 0.4$ T and then approaches $A_R \approx -1$. Taken together, the data in Fig. 1 clearly demonstrate the existence of a mechanism which favors stripes along B_{\parallel} . As we show next, this mechanism is relevant at other filling factors although it shows sensitivity to both the spin index σ and the Landau level index N .

Figure 2 shows the phase diagram of stripe orientations at $\nu = 9/2, 11/2, 13/2$, and $15/2$ for (a) $B_{\parallel} = B_y$ and (b) $B_{\parallel} = B_x$. The regions representing stripes along \hat{y} (\hat{x}), marked by vertical (horizontal) lines, are demarcated by the characteristic fields (circles) where $A_R \approx 0$. We define B_{1y} as the field at which stripes reorient perpendicular to B_y , and B_{2x} (B_{2y}) as the field at which stripes reorient parallel to B_x (B_y). The dashed lines represent B_{\parallel} at select tilt angles and the resistances at these angles are shown in Figs. 2(c) and 2(d). First, we notice that both B_{2x} and B_{2y} increase with N for a given σ , while B_{1y} decreases with N . Second, strong sensitivity to σ renders the overall dependencies of B_{2x} and B_{2y} on ν nonmonotonic;

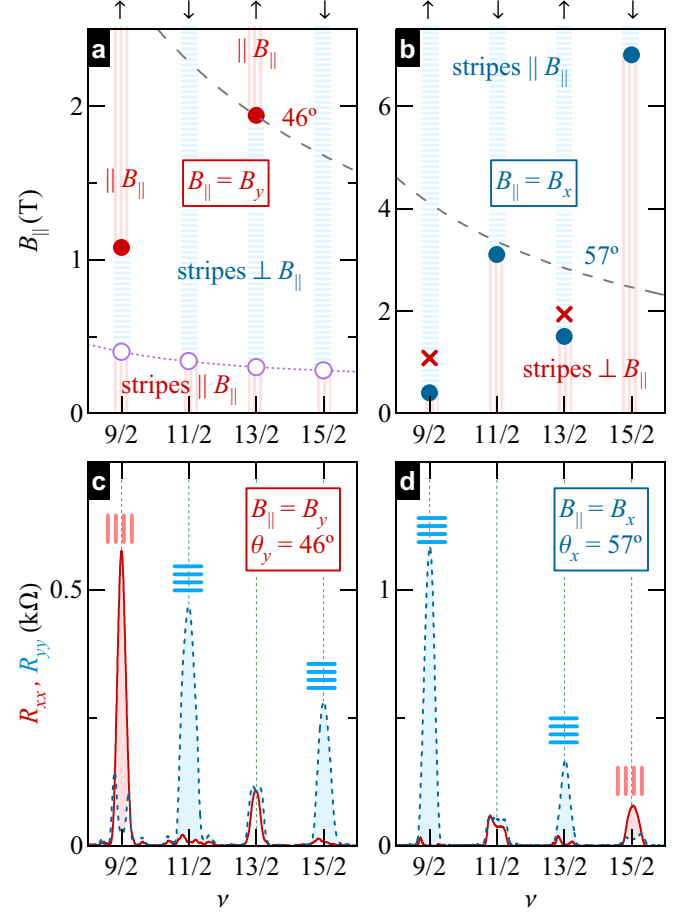


FIG. 2. Evolution of stripe orientation at $\nu = 9/2, 11/2, 13/2$, and $15/2$ for (a) $B_{\parallel} = B_y$ and (b) $B_{\parallel} = B_x$. The regions with vertical (horizontal) lines represent stripes along \hat{y} (\hat{x}), demarcated by the characteristic fields B_{1y} (open dots), B_{2x} [panel (b)] and B_{2y} [panel (a)] (solid dots). For comparison, B_{2y} (crosses) are added to panel (b) at $\nu = 9/2$ and $13/2$. Dashed lines represent B_{\parallel} at marked tilt angles. R_{xx} (solid line) and R_{yy} (dotted line) vs ν at (c) $\theta_y = 46^\circ$ and (d) $\theta_x = 57^\circ$.

indeed, both B_{2x} and B_{2y} are always considerably smaller for $\sigma = +1/2$ than $\sigma = -1/2$.

The sensitivity of B_{2x} and B_{2y} to σ and N is also evident in the raw data presented in Figs. 2(c) and 2(d). For $B_{\parallel} = B_y$ and $\theta_y = 46^\circ$ [see Fig. 2(c)], the stripes at $\nu = 9/2$ have reoriented back to their native direction (along the \hat{y} axis) as manifested by $R_{xx} \gg R_{yy}$. The data at $\nu = 13/2$ suggest that the (second) reorientation is about to happen at this filling factor as well. However, stripes at $\nu = 11/2$ and $15/2$ are still oriented along the \hat{x} direction, as $R_{xx} \ll R_{yy}$. For $B_{\parallel} = B_x$ and $\theta_x = 57^\circ$ [see Fig. 2(d)], stripes both at $\nu = 9/2$ and $13/2$ have reoriented along the \hat{x} axis, stripes at $\nu = 11/2$ are undergoing the reorientation, while stripes at $\nu = 15/2$ are still oriented along the \hat{y} direction.

To compare the magnitudes of B_{2x} and B_{2y} we add B_{2y} (crosses) to Fig. 2(b) and observe that B_{2y} is close to B_{2x} at both $\nu = 9/2$ and $13/2$. Combined with qualitatively identical dependence on σ and N , this observation suggests that the reorientations characterized by B_{2x} and B_{2y} are of similar origin. We can now classify the reorientations into two types.

The first type, which aligns stripes perpendicular to B_{\parallel} , is characterized by B_{1y} that is not sensitive to σ and decreases with N . The second type aligns stripes parallel to B_{\parallel} and is characterized by B_{2x} and B_{2y} that depend on σ [28] and increase with N . The data at $\nu = 9/2$ also suggest that the mechanism responsible for reorientation of the first (second) type dominates at lower (higher) B_{\parallel} .

The reorientation of the first type is well understood in terms of finite thickness effects [17,18]. The B_{\parallel} -induced anisotropy energy can be defined as $E_{1A} = E_{1\parallel} - E_{1\perp}$, where $E_{1\parallel}$ and $E_{1\perp}$ are optimized energies per electron of a stripe state parallel and perpendicular to B_{\parallel} , respectively. For a single-subband system, $E_{1A} > 0$ and increases monotonically with B_{\parallel} [17,21]. While E_{1A} could change sign in systems with two occupied subbands, such systems do not exhibit native stripes at $B_{\parallel} = 0$ and E_{1A} is insensitive to σ [17,27]. We thus conclude that reorientations of the second type, favoring stripes parallel to B_{\parallel} , have a distinct physical origin.

Furthermore, since $E_{1A}(B_x) = E_{1A}(B_y)$ for $B_x = B_y$ [17,18], we can conclude that the mechanism responsible for reorientation of the second type lacks such symmetry. Indeed, if we assume that the anisotropy energy due to the second mechanism, E_{2A} , is the same for B_{\parallel} applied along the \hat{x} or \hat{y} directions, one would expect, in the absence of native symmetry-breaking potential, $B_{2x} = B_{2y}$ at a given ν ; a native symmetry-breaking potential favoring stripes along the \hat{y} direction would then lead to $B_{2x} > B_{2y}$. In contrast, our data show exactly the opposite and, e.g., at $\nu = 9/2$, $B_{2y} \approx 1.0$ T is considerably larger than $B_{2x} \approx 0.4$ T. We thus conclude that E_{2A} must depend on the direction of B_{\parallel} , suggesting possible coupling of B_{\parallel} to native symmetry-breaking potential

[29]. A proposal considering a combination of Rashba and Dresselhaus spin-orbital interactions as the origin of the native symmetry-breaking potential [15,30,31] seems to indicate that the effects of B_{\parallel} on such native stripe states should be sensitive to its orientation with respect to the crystal axes. However, a study of the interplay between B_{\parallel} and spin-orbital interactions was left for future work.

Despite our lack of understanding of the mechanism responsible for the second type of reorientation, our experimental results unambiguously demonstrate that two competing mechanisms must be incorporated in any complete theory of reorientation of quantum Hall nematics. Another important implication of our findings is related to the identification of the native symmetry-breaking potential, whose strength was traditionally obtained by calculating E_{1A} at $B_{\parallel} = B_{1c}$. In light of clear evidence for the second mechanism and its possible coupling to the native symmetry-breaking potential and/or E_{1A} , this approach must be reexamined.

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- [28] Qualitatively consistent with our observations, early experiments [19] have found that, when B_{\parallel} is applied perpendicular to stripes, the anisotropy is affected more at $\nu = 9/2$ and $13/2$ than at $\nu = 11/2$ and $15/2$.
- [29] An alternative scenario is that the effect of B_{\parallel} is modified by disorder which is anisotropic along the two crystal axes [22]. However, effect of disorder on stripes orientation has not been studied theoretically and it seems unlikely that such a mechanism would depend on σ .
- [30] We note that the anisotropy energy due to this mechanism also shows oscillating behavior with σ .
- [31] Recent experiments [13] have found that the quantum well symmetry has a minor role in deciding the stripes orientation, suggesting that spin-orbital interaction [15] is unlikely to be the major mechanism for the native symmetry breaking.